National
Semiconductor

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LMH6618 Single/LMH6619 Dual 130 MHz, 1.25 mA RRIO Operational Amplifiers

General Description

The LMH6618 (single, with shutdown) and LMH6619 (dual) are 130 MHz rail-to-rail input and output amplifiers designed for ease of use in a wide range of applications requiring high speed, low supply current, low noise, and the ability to drive complex ADC and video loads. The operating voltage range extends from 2.7V to 11V and the supply current is typically 1.25 mA per channel at 5V. The LMH6618 and LMH6619 are members of the PowerWise® family and have an exceptional power-to-performance ratio.

The amplifier's voltage feedback design topology provides balanced inputs and high open loop gain for ease of use and accuracy in applications such as active filter design. Offset voltage is typically 0.1 mV and settling time to 0.01% is 120 ns which combined with an 100 dBc SFDR at 100 kHz makes the part suitable for use as an input buffer for popular 8-bit, 10-bit, 12-bit and 14-bit mega-sample ADCs.

The input common mode range extends 200 mV beyond the supply rails. On a single 5V supply with a ground terminated 150Ω load the output swings to within 37 mV of the ground rail, while a mid-rail terminated 1 kΩ load will swing to 77 mV of either rail, providing true single supply operation and maximum signal dynamic range on low power rails. The amplifier output will source and sink 35 mA and drive up to 30 pF loads without the need for external compensation.

The LMH6618 has an active low disable pin which reduces the supply current to 72 µA and is offered in the space saving 6-Pin TSOT23 package. The LMH6619 is offered in the 8-Pin SOIC package. The LMH6618 and LMH6619 are available with a −40°C to +125°C extended industrial temperature grade.

Features

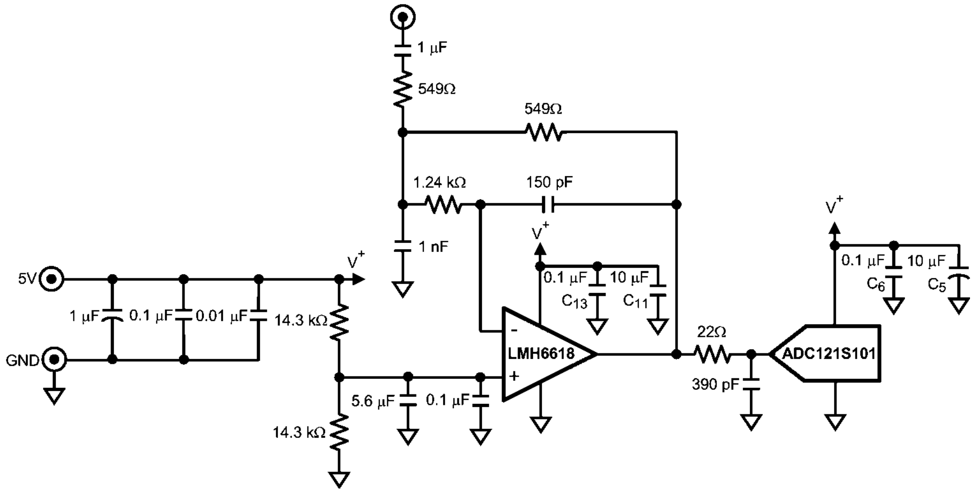
V_S = 5V, R_L = 1 kΩ, T_A = 25°C and A_V = +1, unless otherwise specified.

Operating voltage range	2.7V to 11V
Supply current per channel	1.25 mA
Small signal bandwidth	130 MHz
Input offset voltage (limit at 25°C)	±0.6 mV
Slew rate	55 V/µs
Settling time to 0.1%	90 ns
Settling time to 0.01%	120 ns
SFDR (f = 100 kHz, A_V = +1, V_{OUT} = 2 V_{PP})	100 dBc
0.1 dB bandwidth (A_V = +2)	15 MHz
Low voltage noise	10 nV/√Hz
Industrial temperature grade	−40°C to +125°C
Rail-to-Rail input and output	

Applications

- ADC driver
- DAC buffer
- Active filters
- High speed sensor amplifier
- Current sense amplifier
- Portable video
- STB, TV video amplifier

Typical Application



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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

ESD Tolerance (Note 2)	
Human Body Model	
For input pins only	2000V
For all other pins	2000V
Machine Model	200V
Supply Voltage ($V_S = V^+ - V^-$)	12V
Junction Temperature (Note 3)	150°C max

Operating Ratings (Note 1)

Supply Voltage ($V_S = V^+ - V^-$)	2.7V to 11V
Ambient Temperature Range (Note 3)	−40°C to +125°C
Package Thermal Resistance (θ_{JA})	
6-Pin TSOT23	231°C/W
8-Pin SOIC	160°C/W

+3V Electrical Characteristics

Unless otherwise specified, all limits are guaranteed for $T_J = +25°C$, $V^+ = 3V$, $V^- = 0V$, $\overline{DISABLE} = 3V$, $V_{CM} = V_O = V^+/2$, $A_V = +1$ ($R_F = 0\Omega$), otherwise $R_F = 2\ k\Omega$ for $A_V \neq +1$, $R_L = 1\ k\Omega\ ||\ 5\ pF$. **Boldface** Limits apply at temperature extremes. (Note 4)

Symbol	Parameter	Condition	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Units
Frequency Domain Response						
SSBW	−3 dB Bandwidth Small Signal	$A_V = 1$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$		120		MHz
		$A_V = 2, -1$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$		56		
GBW	Gain Bandwidth (LMH6618)	$A_V = 10$, $R_F = 2\ k\Omega$, $R_G = 221\Omega$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$	55	71		MHz
GBW	Gain Bandwidth (LMH6619)	$A_V = 10$, $R_F = 2\ k\Omega$, $R_G = 221\Omega$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$	55	63		MHz
LSBW	−3 dB Bandwidth Large Signal	$A_V = 1$, $R_L = 1\ k\Omega$, $V_{OUT} = 2\ V_{PP}$		13		MHz
		$A_V = 2$, $R_L = 150\Omega$, $V_{OUT} = 2\ V_{PP}$		13		
Peak	Peaking	$A_V = 1$, $C_L = 5\ pF$		1.5		dB
0.1 dBBW	0.1 dB Bandwidth	$A_V = 2$, $V_{OUT} = 0.5\ V_{PP}$, $R_F = R_G = 825\Omega$		15		MHz
DG	Differential Gain	$A_V = +2$, 4.43 MHz, $0.6V < V_{OUT} < 2V$, $R_L = 150\Omega$ to $V^+/2$		0.1		%
DP	Differential Phase	$A_V = +2$, 4.43 MHz, $0.6V < V_{OUT} < 2V$, $R_L = 150\Omega$ to $V^+/2$		0.1		deg
Time Domain Response						
t_r/t_f	Rise & Fall Time	2V Step, $A_V = 1$		36		ns
SR	Slew Rate	2V Step, $A_V = 1$	36	46		V/μs
$t_{s\_0.1}$	0.1% Settling Time	2V Step, $A_V = -1$		90		ns
$t_{s\_0.01}$	0.01% Settling Time	2V Step, $A_V = -1$		120		
Noise and Distortion Performance						
SFDR	Spurious Free Dynamic Range	$f_C = 100\ kHz$, $V_{OUT}= 2\ V_{PP}$, $R_L = 1\ k\Omega$		100		dBc
		$f_C = 1\ MHz$, $V_{OUT} = 2\ V_{PP}$, $R_L = 1\ k\Omega$		61		
		$f_C = 5\ MHz$, $V_{OUT} = 2\ V_{PP}$, $R_L = 1\ k\Omega$		47		
e_n	Input Voltage Noise Density	f = 100 kHz		10		$nV/\sqrt{Hz}$
i_n	Input Current Noise Density	f = 100 kHz		1		$pA/\sqrt{Hz}$
CT	Crosstalk (LMH6619)	$f = 5\ MHz$, $V_{IN} = 2\ V_{PP}$		80		dB
Input, DC Performance						
V_{OS}	Input Offset Voltage	$V_{CM} = 0.5V$ (pnp active) $V_{CM} = 2.5V$ (npn active)		0.1	±0.6 **±1.0**	mV
TCV_{OS}	Input Offset Voltage Temperature Drift	(Note 5)		0.8		μV/°C
I_B	Input Bias Current	$V_{CM} = 0.5V$ (pnp active)		−1.4	**−2.6**	μA
		$V_{CM} = 2.5V$ (npn active)		+1.0	**+1.8**	
I_{OS}	Input Offset Current			0.01	**±0.27**	μA

Symbol	Parameter	Condition	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Units
C_{IN}	Input Capacitance			1.5		pF
R_{IN}	Input Resistance			8		MΩ
CMVR	Common Mode Voltage Range	DC, CMRR ≥ 65 dB	−0.2		3.2	V
CMRR	Common Mode Rejection Ratio	V_{CM} Stepped from −0.1V to 1.4V	78	96		dB
		V_{CM} Stepped from 2.0V to 3.1V	81	107		
A_{OL}	Open Loop Voltage Gain	R_L = 1 kΩ to +2.7V or +0.3V	85	98		dB
		R_L = 150Ω to +2.6V or +0.4V	76	82		
Output DC Characteristics						
V_{OUT}	Output Voltage Swing High (LMH6618) (Voltage from V^+ Supply Rail)	R_L = 1 kΩ to $V^+/2$		50	56 **62**	mV from either rail
		R_L =150Ω to $V^+/2$		160	172 **198**	
	Output Voltage Swing Low (LMH6618) (Voltage from V^- Supply Rail)	R_L = 1 kΩ to $V^+/2$		60	66 **74**	
		R_L = 150Ω to $V^+/2$		170	184 **217**	
		R_L = 150Ω to V^-		29	39 **43**	
	Output Voltage Swing High (LMH6619) (Voltage from V^+ Supply Rail)	R_L = 1 kΩ to $V^+/2$		50	56 **62**	mV from either rail
		R_L =150Ω to $V^+/2$		160	172 **198**	
	Output Voltage Swing Low (LMH6619) (Voltage from V^- Supply Rail)	R_L = 1 kΩ to $V^+/2$		62	68 **76**	
		R_L =150Ω to $V^+/2$		175	189 **222**	
		R_L = 150Ω to V^-		34	44 **48**	
I_{OUT}	Linear Output Current	V_{OUT} = $V^+/2$ (Note 6)	±25	±35		mA
R_{OUT}	Output Resistance	f = 1 MHz		0.17		Ω
Enable Pin Operation						
	Enable High Voltage Threshold	Enabled	2.0			V
	Enable Pin High Current	$V_{\overline{DISABLE}}$ = 3V		0.04		μA
	Enable Low Voltage Threshold	Disabled			1.0	V
	Enable Pin Low Current	$V_{\overline{DISABLE}}$ = 0V		1		μA
t_{on}	Turn-On Time			25		ns
t_{off}	Turn-Off Time			90		ns
Power Supply Performance						
PSRR	Power Supply Rejection Ratio	DC, V_{CM} = 0.5V, V_S = 2.7V to 11V	84	104		dB
I_S	Supply Current (LMH6618)	R_L = ∞		1.2	1.5 **1.7**	mA
	Supply Current (LMH6619) (per channel)	R_L = ∞		1.2	1.5 **1.75**	
I_{SD}	Disable Shutdown Current	$\overline{DISABLE}$ = 0V		59	85	μA

+5V Electrical Characteristics

Unless otherwise specified, all limits are guaranteed for $T_J = +25°C$, $V^+ = 5V$, $V^- = 0V$, $\overline{DISABLE} = 5V$, $V_{CM} = V_O = V^+/2$, $A_V = +1$ ($R_F = 0\Omega$), otherwise $R_F = 2\ k\Omega$ for $A_V \neq +1$, $R_L = 1\ k\Omega \parallel 5\ pF$. **Boldface** Limits apply at temperature extremes.

Symbol	Parameter	Condition	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Units
Frequency Domain Response						
SSBW	–3 dB Bandwidth Small Signal	$A_V = 1$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$		130		MHz
		$A_V = 2, -1$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$		53		
GBW	Gain Bandwidth (LMH6618)	$A_V = 10$, $R_F = 2\ k\Omega$, $R_G = 221\Omega$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$	54	64		MHz
GBW	Gain Bandwidth (LMH6619)	$A_V = 10$, $R_F = 2\ k\Omega$, $R_G = 221\Omega$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$	54	57		MHz
LSBW	–3 dB Bandwidth Large Signal	$A_V = 1$, $R_L = 1\ k\Omega$, $V_{OUT} = 2\ V_{PP}$		15		MHz
		$A_V = 2$, $R_L = 150\Omega$, $V_{OUT} = 2\ V_{PP}$		15		
Peak	Peaking	$A_V = 1$, $C_L = 5\ pF$		0.5		dB
0.1 dBBW	0.1 dB Bandwidth	$A_V = 2$, $V_{OUT} = 0.5\ V_{PP}$, $R_F = R_G = 1\ k\Omega$		15		MHz
DG	Differential Gain	$A_V = +2$, 4.43 MHz, $0.6V < V_{OUT} < 2V$, $R_L = 150\Omega$ to $V^+/2$		0.1		%
DP	Differential Phase	$A_V = +2$, 4.43 MHz, $0.6V < V_{OUT} < 2V$, $R_L = 150\Omega$ to $V^+/2$		0.1		deg
Time Domain Response						
t_r/t_f	Rise & Fall Time	2V Step, $A_V = 1$		30		ns
SR	Slew Rate	2V Step, $A_V = 1$	44	55		V/µs
$t_{s\_0.1}$	0.1% Settling Time	2V Step, $A_V = -1$		90		ns
$t_{s\_0.01}$	0.01% Settling Time	2V Step, $A_V = -1$		120		
Distortion and Noise Performance						
SFDR	Spurious Free Dynamic Range	$f_C = 100\ kHz$, $V_{OUT} = 2\ V_{PP}$, $R_L = 1\ k\Omega$		100		dBc
		$f_C = 1\ MHz$, $V_{OUT} = 2\ V_{PP}$, $R_L = 1\ k\Omega$		88		
		$f_C = 5\ MHz$, $V_O = 2\ V_{PP}$, $R_L = 1\ k\Omega$		61		
e_n	Input Voltage Noise Density	f = 100 kHz		10		$nV/\sqrt{Hz}$
i_n	Input Current Noise Density	f = 100 kHz		1		$pA/\sqrt{Hz}$
CT	Crosstalk (LMH6619)	$f = 5\ MHz$, $V_{IN} = 2\ V_{PP}$		80		dB
Input, DC Performance						
V_{OS}	Input Offset Voltage	$V_{CM} = 0.5V$ (pnp active) $V_{CM} = 4.5V$ (npn active)		0.1	±0.6 **±1.0**	mV
TCV_{OS}	Input Offset Voltage Temperature Drift	(Note 5)		0.8		µV/°C
I_B	Input Bias Current	$V_{CM} = 0.5V$ (pnp active)		−1.5	**−2.4**	µA
		$V_{CM} = 4.5V$ (npn active)		+1.0	**+1.9**	
I_{OS}	Input Offset Current			0.01	**±0.26**	µA
C_{IN}	Input Capacitance			1.5		pF
R_{IN}	Input Resistance			8		MΩ
CMVR	Common Mode Voltage Range	DC, CMRR ≥ 65 dB	−0.2		5.2	V
CMRR	Common Mode Rejection Ratio	V_{CM} Stepped from −0.1V to 3.4V	81	98		dB
		V_{CM} Stepped from 4.0V to 5.1V	84	108		
A_{OL}	Open Loop Voltage Gain	$R_L = 1\ k\Omega$ to +4.6V or +0.4V	84	100		dB
		$R_L = 150\Omega$ to +4.5V or +0.5V	78	83		

Symbol	Parameter	Condition	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Units
Output DC Characteristics						
V_{OUT}	Output Voltage Swing High (LMH6618) (Voltage from V^+ Supply Rail)	$R_L = 1\ k\Omega$ to $V^+/2$		60	73 **82**	mV from either rail
		$R_L = 150\Omega$ to $V^+/2$		230	255 **295**	
	Output Voltage Swing Low (LMH6618) (Voltage from V^- Supply Rail)	$R_L = 1\ k\Omega$ to $V^+/2$		75	83 **96**	
		$R_L = 150\Omega$ to $V^+/2$		250	270 **321**	
		$R_L = 150\Omega$ to V^-		32	43 **45**	
	Output Voltage Swing High (LMH6619) (Voltage from V^+ Supply Rail)	$R_L = 1\ k\Omega$ to $V^+/2$		60	73 **82**	mV from either rail
		$R_L = 150\Omega$ to $V^+/2$		230	255 **295**	
	Output Voltage Swing Low (LMH6619) (Voltage from V^- Supply Rail)	$R_L = 1\ k\Omega$ to $V^+/2$		77	85 **98**	
		$R_L = 150\Omega$ to $V^+/2$		255	275 **326**	
		$R_L = 150\Omega$ to V^-		37	48 **50**	
I_{OUT}	Linear Output Current	$V_{OUT} = V^+/2$ (Note 6)	±25	±35		mA
R_{OUT}	Output Resistance	f = 1 MHz		0.17		Ω
Enable Pin Operation						
	Enable High Voltage Threshold	Enabled	3.0			V
	Enable Pin High Current	$V_{\overline{DISABLE}} = 5V$		1.2		μA
	Enable Low Voltage Threshold	Disabled			2.0	V
	Enable Pin Low Current	$V_{\overline{DISABLE}} = 0V$		2.5		μA
t_{on}	Turn-On Time			25		ns
t_{off}	Turn-Off Time			90		ns
Power Supply Performance						
PSRR	Power Supply Rejection Ratio	DC, $V_{CM} = 0.5V$, $V_S = 2.7V$ to 11V	84	104		dB
I_S	Supply Current (LMH6618)	$R_L = \infty$		1.25	1.5 **1.7**	mA
	Supply Current (LMH6619) (per channel)	$R_L = \infty$		1.3	1.5 **1.75**	
I_{SD}	Disable Shutdown Current	$\overline{DISABLE}$ = 0V		72	105	μA

±5V Electrical Characteristics

Unless otherwise specified, all limits are guaranteed for $T_J = +25°C$, $V^+ = 5V$, $V^- = -5V$, $\overline{DISABLE} = 5V$, $V_{CM} = V_O = 0V$, $A_V = +1$ ($R_F = 0\Omega$), otherwise $R_F = 2\ k\Omega$ for $A_V \neq +1$, $R_L = 1\ k\Omega \parallel 5\ pF$. **Boldface** Limits apply at temperature extremes.

Symbol	Parameter	Condition	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Units
Frequency Domain Response						
SSBW	–3 dB Bandwidth Small Signal	$A_V = 1$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$		140		MHz
		$A_V = 2, -1$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$		53		
GBW	Gain Bandwidth (LMH6618)	$A_V = 10$, $R_F = 2\ k\Omega$, $R_G = 221\Omega$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$	54	65		MHz
GBW	Gain Bandwidth (LMH6619)	$A_V = 10$, $R_F = 2\ k\Omega$, $R_G = 221\Omega$, $R_L = 1\ k\Omega$, $V_{OUT} = 0.2\ V_{PP}$	54	58		MHz

Symbol	Parameter	Condition	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Units
LSBW	−3 dB Bandwidth Large Signal	$A_V = 1$, $R_L = 1\ k\Omega$, $V_{OUT} = 2\ V_{PP}$		16		MHz
		$A_V = 2$, $R_L = 150\Omega$, $V_{OUT} = 2\ V_{PP}$		15		
Peak	Peaking	$A_V = 1$, $C_L = 5\ pF$		0.05		dB
0.1 dBBW	0.1 dB Bandwidth	$A_V = 2$, $V_{OUT} = 0.5\ V_{PP}$, $R_F = R_G = 1.21\ k\Omega$		15		MHz
DG	Differential Gain	$A_V = +2$, 4.43 MHz, $0.6V < V_{OUT} < 2V$, $R_L = 150\Omega$ to $V^+/2$		0.1		%
DP	Differential Phase	$A_V = +2$, 4.43 MHz, $0.6V < V_{OUT} < 2V$, $R_L = 150\Omega$ to $V^+/2$		0.1		deg
Time Domain Response						
t_r/t_f	Rise & Fall Time	2V Step, $A_V = 1$		30		ns
SR	Slew Rate	2V Step, $A_V = 1$	45	57		V/μs
$t_{s\_0.1}$	0.1% Settling Time	2V Step, $A_V = -1$		90		ns
$t_{s\_0.01}$	0.01% Settling Time	2V Step, $A_V = -1$		120		
Noise and Distortion Performance						
SFDR	Spurious Free Dynamic Range	$f_C = 100\ kHz$, $V_{OUT} = 2\ V_{PP}$, $R_L = 1\ k\Omega$		100		dBc
		$f_C = 1\ MHz$, $V_{OUT} = 2\ V_{PP}$, $R_L = 1\ k\Omega$		88		
		$f_C = 5\ MHz$, $V_{OUT} = 2\ V_{PP}$, $R_L = 1\ k\Omega$		70		
e_n	Input Voltage Noise Density	f = 100 kHz		10		nV/$\sqrt{Hz}$
i_n	Input Current Noise Density	f = 100 kHz		1		pA/$\sqrt{Hz}$
CT	Crosstalk (LMH6619)	f = 5 MHz, $V_{IN} = 2\ V_{PP}$		80		dB
Input DC Performance						
V_{OS}	Input Offset Voltage	$V_{CM} = -4.5V$ (pnp active) $V_{CM} = 4.5V$ (npn active)		0.1	±0.6 **±1.0**	mV
TCV_{OS}	Input Offset Voltage Temperature Drift	(Note 5)		0.9		μV/°C
I_B	Input Bias Current	$V_{CM} = -4.5V$ (pnp active)		−1.5	**−2.4**	μA
		$V_{CM} = 4.5V$ (npn active)		+1.0	**+1.9**	
I_{OS}	Input Offset Current			0.01	**±0.26**	μA
C_{IN}	Input Capacitance			1.5		pF
R_{IN}	Input Resistance			8		MΩ
CMVR	Common Mode Voltage Range	DC, CMRR ≥ 65 dB	−5.2		5.2	V
CMRR	Common Mode Rejection Ratio	V_{CM} Stepped from −5.1V to 3.4V	84	100		dB
		V_{CM} Stepped from 4.0V to 5.1V	83	108		
A_{OL}	Open Loop Voltage Gain	$R_L = 1\ k\Omega$ to +4.6V or −4.6V	86	95		dB
		$R_L = 150\Omega$ to +4.3V or −4.3V	79	84		

Symbol	Parameter	Condition	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Units
Output DC Characteristics						
V_{OUT}	Output Voltage Swing High (LMH6618) (Voltage from V^+ Supply Rail)	R_L = 1 kΩ to GND		100	111 **126**	mV from either rail
		R_L = 150Ω to GND		430	457 **526**	
	Output Voltage Swing Low (LMH6618) (Voltage from V^- Supply Rail)	R_L = 1 kΩ to GND		110	121 **136**	
		R_L = 150Ω to GND		440	474 **559**	
		R_L = 150Ω to V^-		35	51 **52**	
	Output Voltage Swing High (LMH6619) (Voltage from V^+ Supply Rail)	R_L = 1 kΩ to GND		100	111 **126**	mV from either rail
		R_L = 150Ω to GND		430	457 **526**	
	Output Voltage Swing Low (LMH6619) (Voltage from V^- Supply Rail)	R_L = 1 kΩ to GND		115	126 **141**	
		R_L = 150Ω to GND		450	484 **569**	
		R_L = 150Ω to V^-		45	61 **62**	
I_{OUT}	Linear Output Current	$V_{OUT} = V^+/2$ (Note 6)	±25	±35		mA
R_{OUT}	Output Resistance	f = 1 MHz		0.17		Ω
Enable Pin Operation						
	Enable High Voltage Threshold	Enabled	0.5			V
	Enable Pin High Current	$V_{\overline{DISABLE}}$ = +5V		16		μA
	Enable Low Voltage Threshold	Disabled			−0.5	V
	Enable Pin Low Current	$V_{\overline{DISABLE}}$ = −5V		17		μA
t_{on}	Turn-On Time			25		ns
t_{off}	Turn-Off Time			90		ns
Power Supply Performance						
PSRR	Power Supply Rejection Ratio	DC, V_{CM} = −4.5V, V_S = 2.7V to 11V	84	104		dB
I_S	Supply Current (LMH6618)	$R_L = \infty$		1.35	1.6 **1.9**	mA
	Supply Current (LMH6619) (per channel)	$R_L = \infty$		1.45	1.65 **2.0**	
I_{SD}	Disable Shutdown Current	$\overline{DISABLE}$ = −5V		103	140	μA

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 2: Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

Note 3: The maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA}. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly onto a PC Board.

Note 4: Boldface limits apply to temperature range of −40°C to 125°C

Note 5: Voltage average drift is determined by dividing the change in V_{OS} by temperature change.

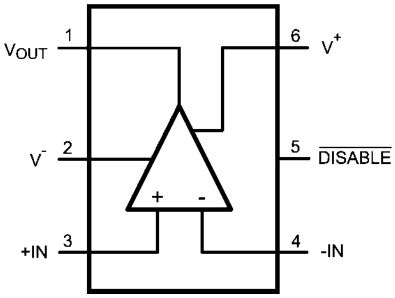
Note 6: Do not short circuit the output. Continuous source or sink currents larger than the I_{OUT} typical are not recommended as it may damage the part.

Note 7: Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

Note 8: Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlations using the Statistical Quality Control (SQC) method.

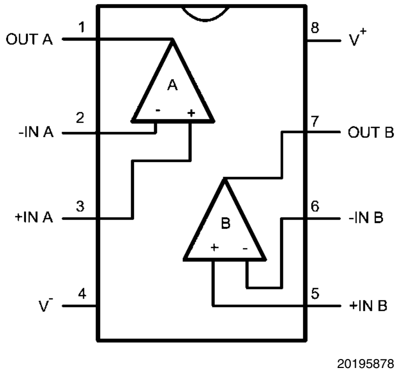
Connection Diagrams

6-Pin TSOT23



Top View

8-Pin SOIC



Top View

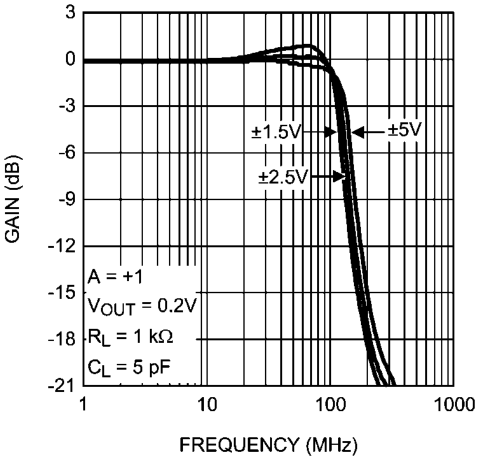
Ordering Information

Package	Part Number	Package Marking	Transport Media	NSC Drawing
6-Pin TSOT23	LMH6618MK	AE4A	1k Units Tape and Reel	MK06A
	LMH6618MKE		250 Units Tape and Reel	
	LMH6618MKX		3k Units Tape and Reel	
8-Pin SOIC	LMH6619MA	LMH6619MA	95 Units/Rail	M08A
	LMH6619MAE		250 Units Tape and Reel	
	LMH6619MAX		2.5k Units Tape and Reel	

Typical Performance Characteristics

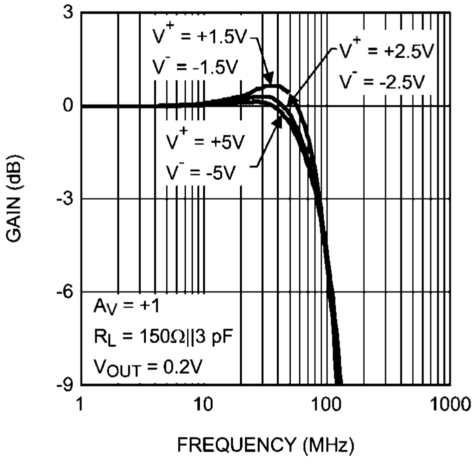
At $T_J = 25°C$, $A_V = +1$ ($R_F = 0\Omega$), otherwise $R_F = 2\ k\Omega$ for $A_V \neq +1$, unless otherwise specified.

Closed Loop Frequency Response for Various Supplies



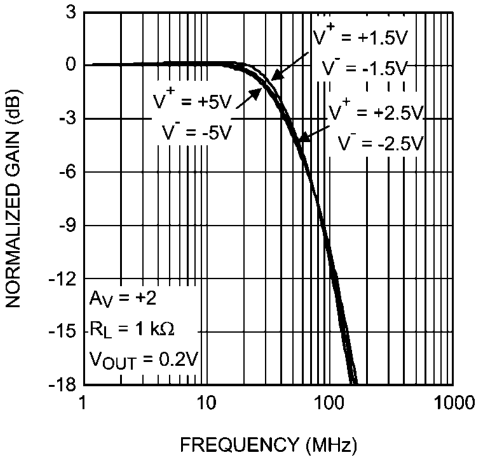
20195831

Closed Loop Frequency Response for Various Supplies



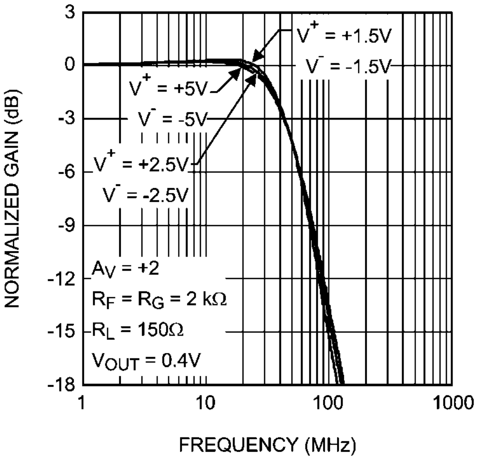
20195816

Closed Loop Frequency Response for Various Supplies



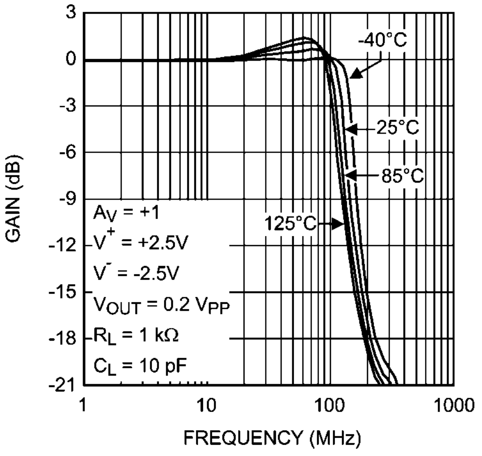
20195815

Closed Loop Frequency Response for Various Supplies



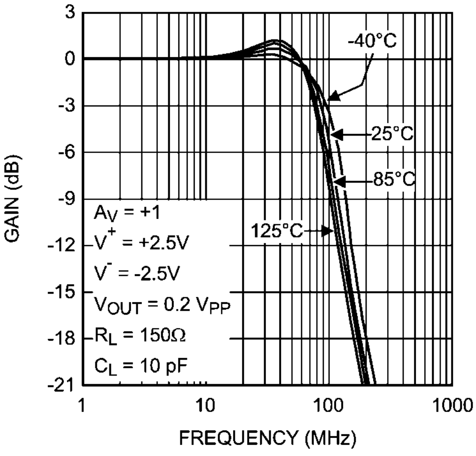
20195817

Closed Loop Frequency Response for Various Temperatures



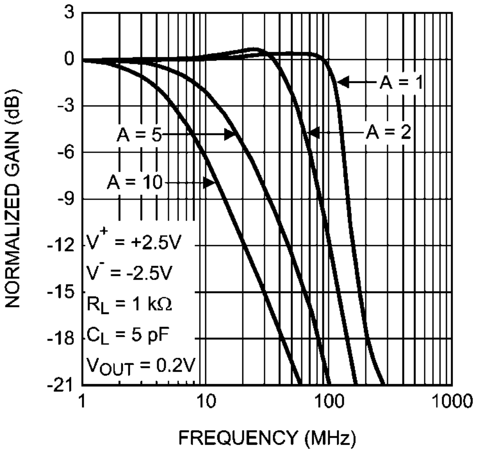
20195819

Closed Loop Frequency Response for Various Temperatures



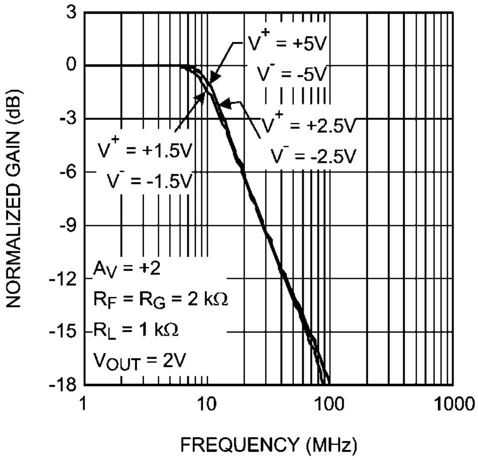
20195820

Closed Loop Gain vs. Frequency for Various Gains



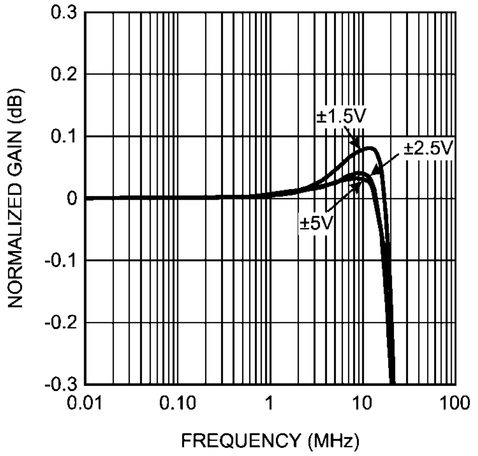
20195830

Large Signal Frequency Response



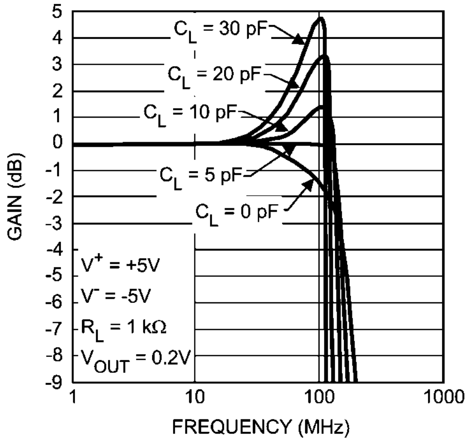
20195818

±0.1 dB Gain Flatness for Various Supplies



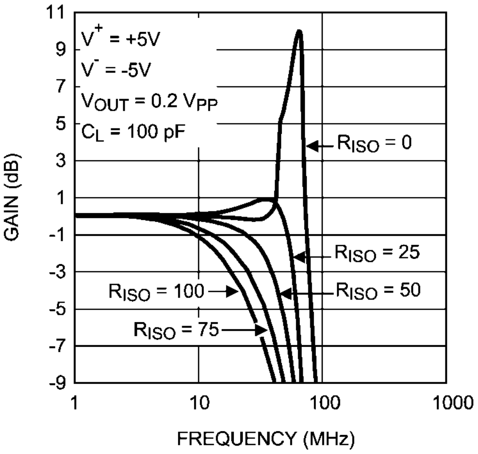
20195832

Small Signal Frequency Response with Various Capacitive Load



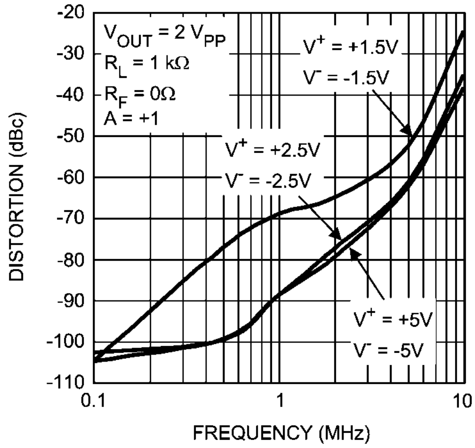
20195826

Small Signal Frequency Response with Capacitive Load and Various R_{ISO}



20195827

HD2 vs. Frequency and Supply Voltage



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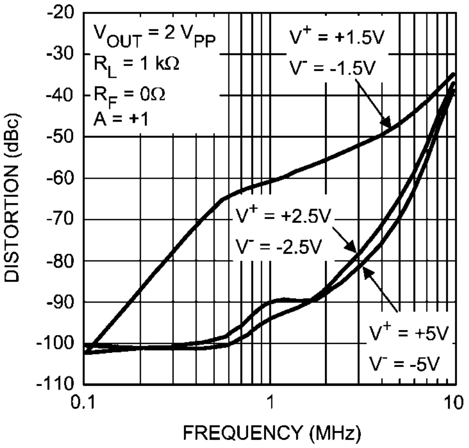
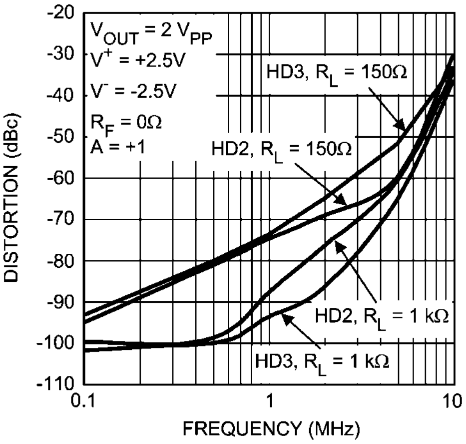


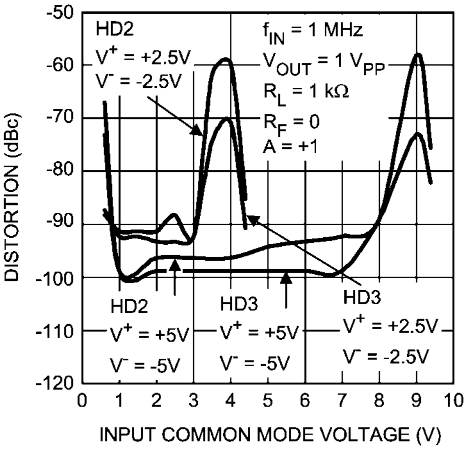
HD3 vs. Frequency and Supply Voltage

20195836



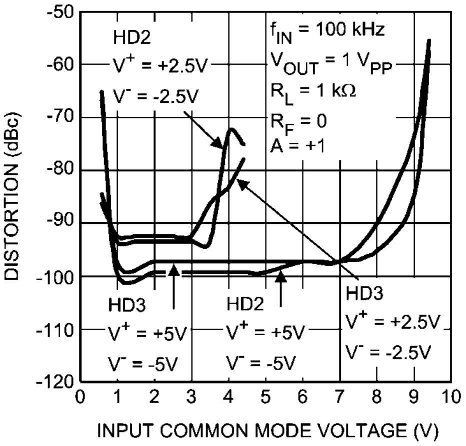
HD2 and HD3 vs. Frequency and Load

20195871



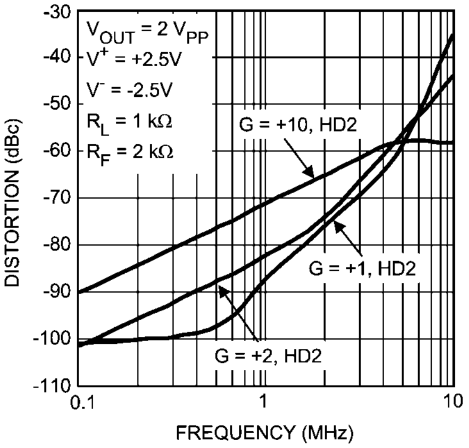
HD2 and HD3 vs. Common Mode Voltage

20195872



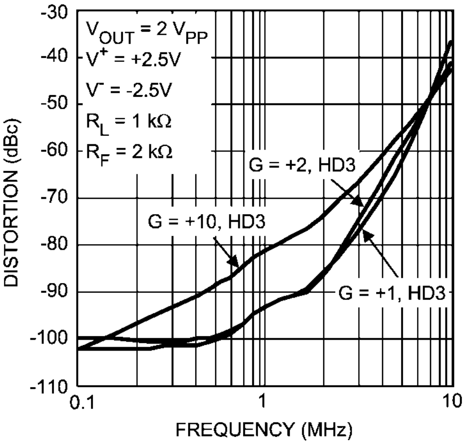
HD2 and HD3 vs. Common Mode Voltage

20195873



HD2 vs. Frequency and Gain

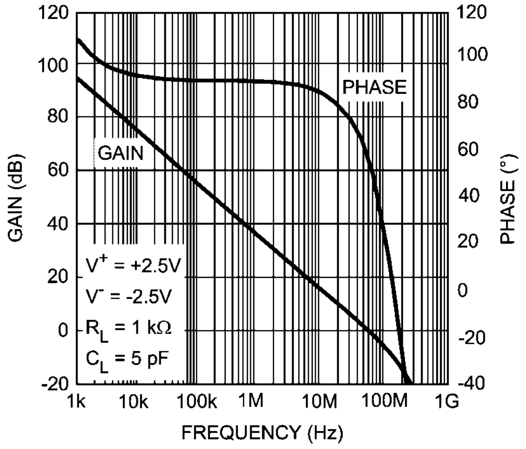
20195874



HD3 vs. Frequency and Gain

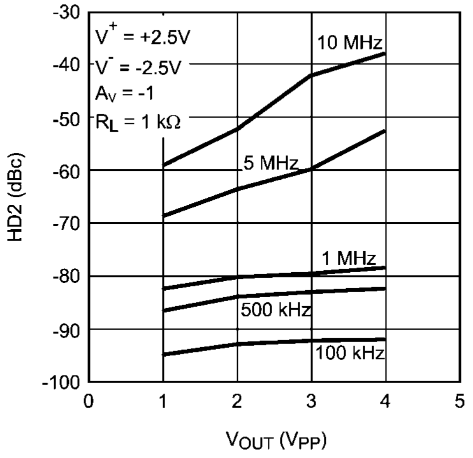
20195875

Open Loop Gain/Phase



20195833

HD2 vs. Output Swing



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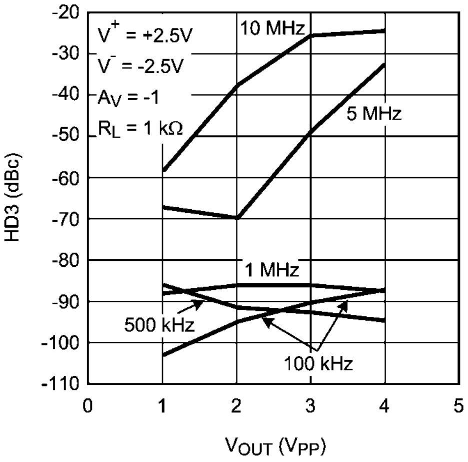
HD3 vs. Output Swing



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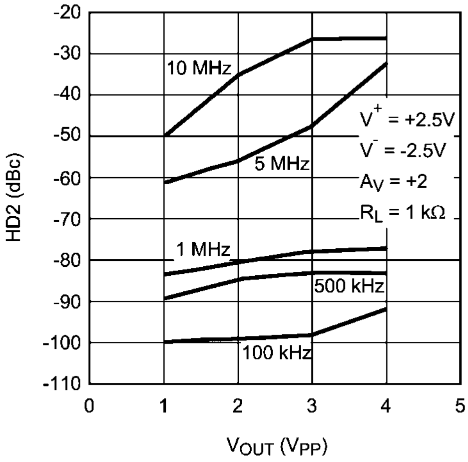
HD2 vs. Output Swing



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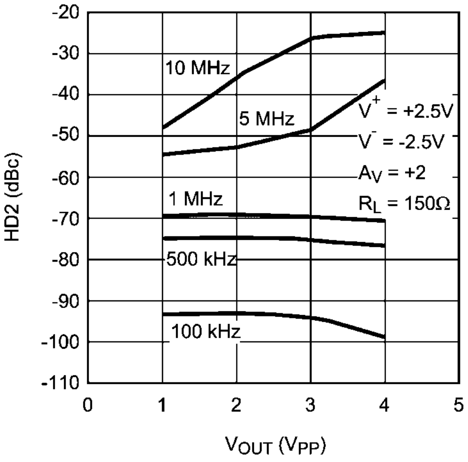
HD2 vs. Output Swing



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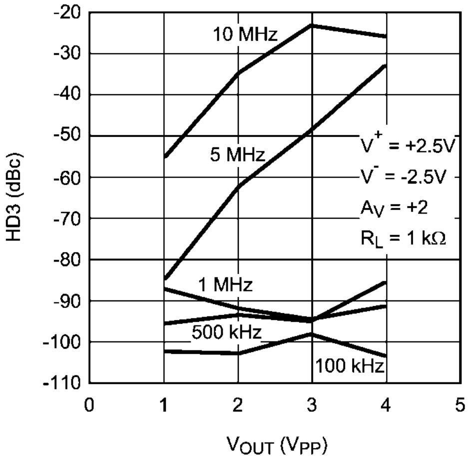
HD3 vs. Output Swing



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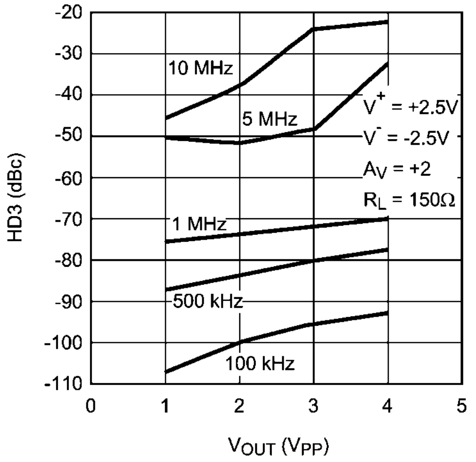
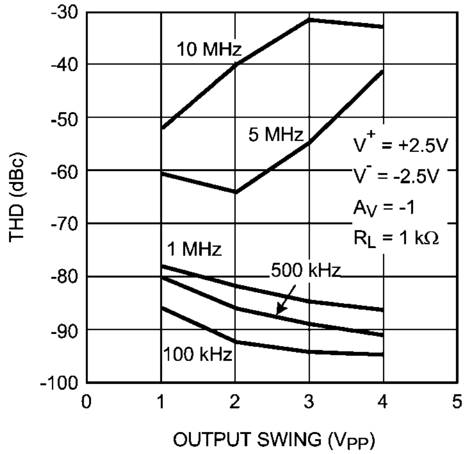
HD3 vs. Output Swing



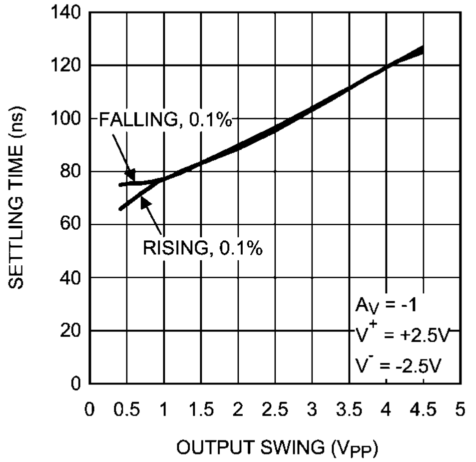
20195870

THD vs. Output Swing



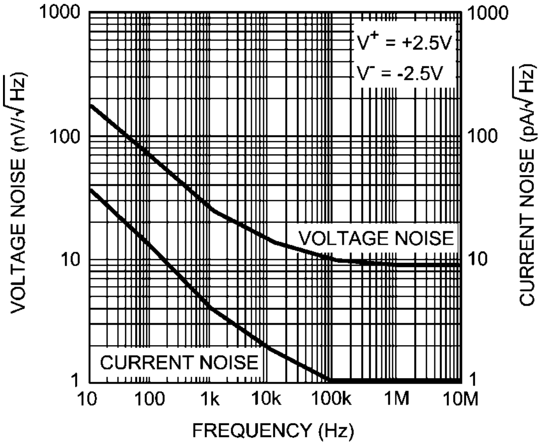
20195847

Settling Time vs. Input Step Amplitude (Output Slew and Settle Time)



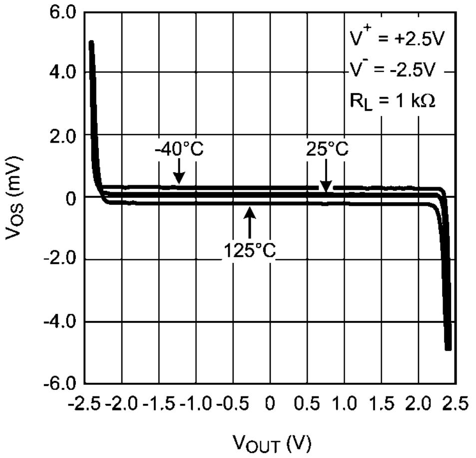
20195821

Input Noise vs. Frequency



20195876

V_{OS} vs. V_{OUT}



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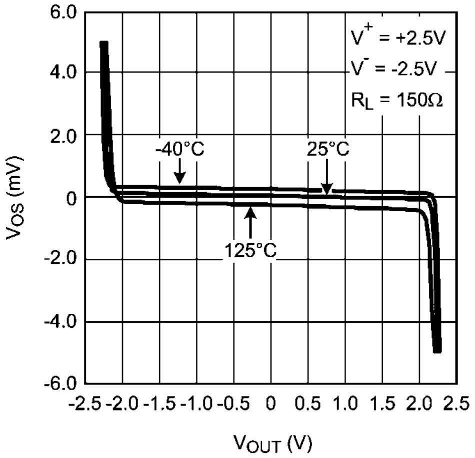
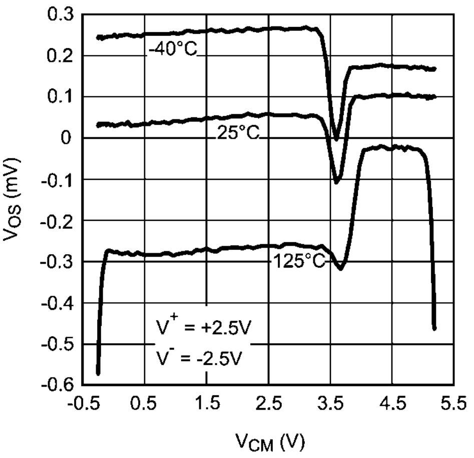
V_{OS} vs. V_{OUT}



20195850

V_{OS} vs. V_{CM}



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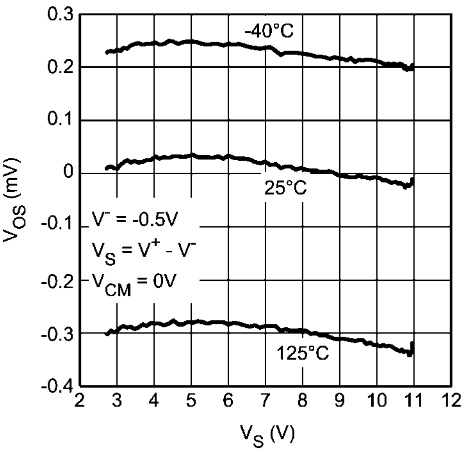
V_{OS} vs. V_S (pnp)



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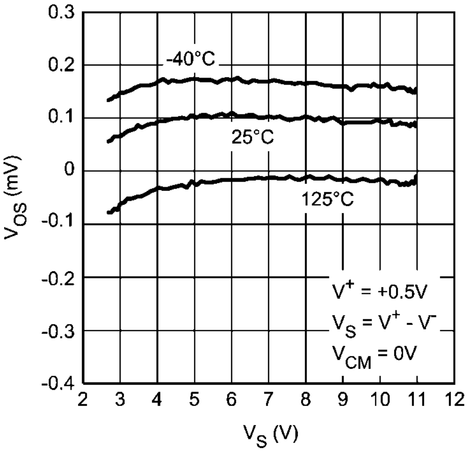
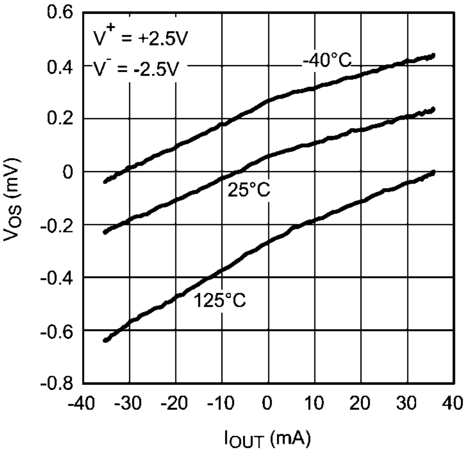
V_{OS} vs. V_S (npn)



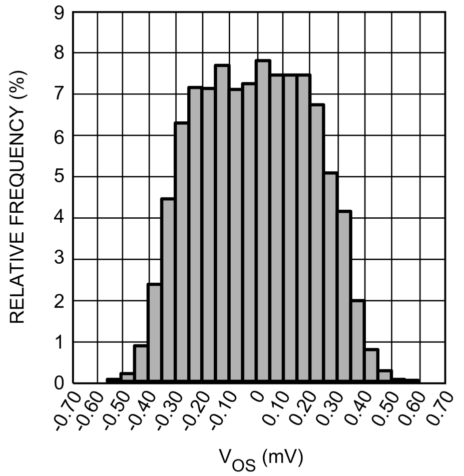
20195853

V_{OS} vs. I_{OUT}



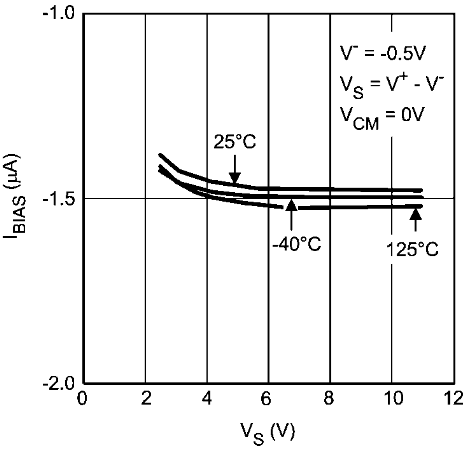
20195854

V_{OS} Distribution (pnp and npn)



20195877

I_B vs. V_S (pnp)



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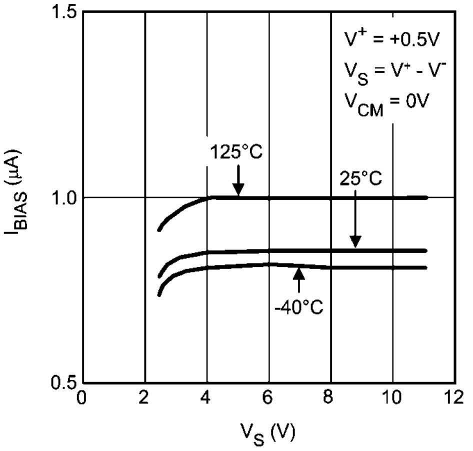
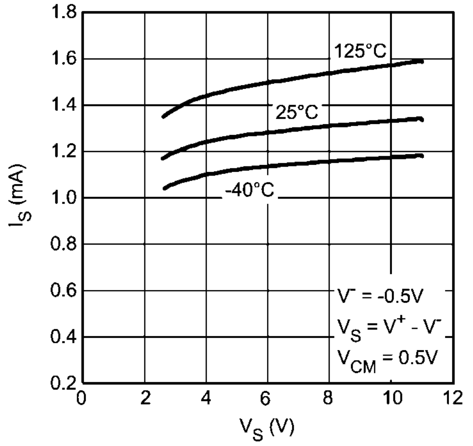
I_B vs. V_S (npn)



20195856

I_S vs. V_S



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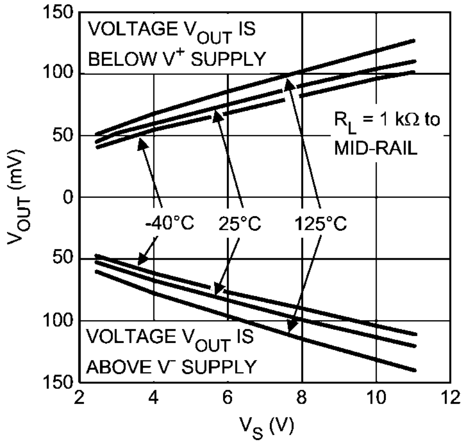
V_{OUT} vs. V_S



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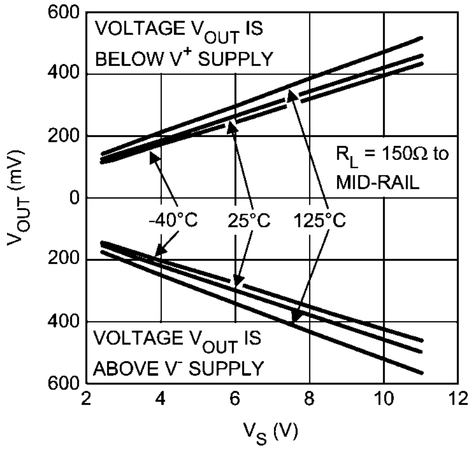
V_{OUT} vs. V_S



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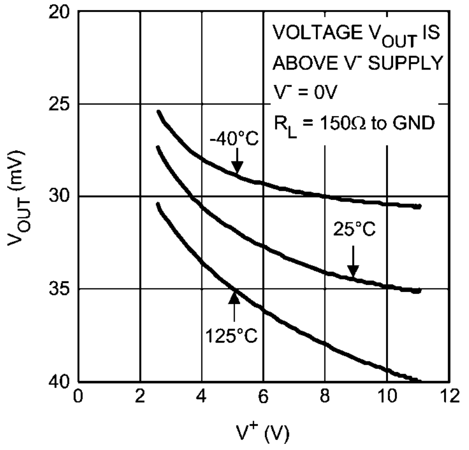
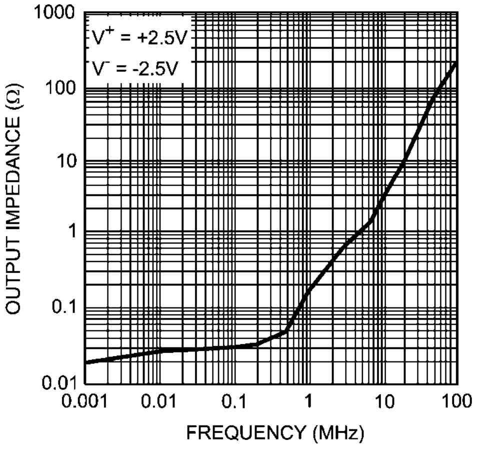
V_{OUT} vs. V_S



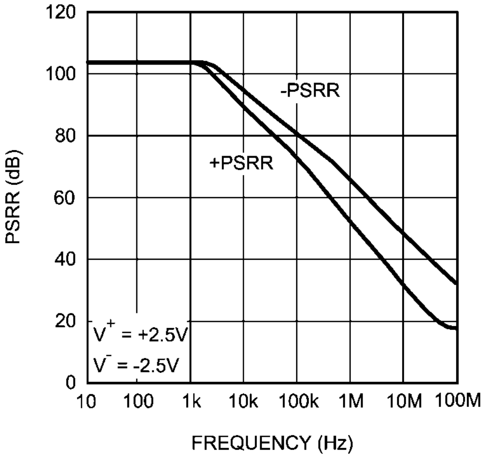
20195860

Closed Loop Output Impedance vs. Frequency $A_V = +1$



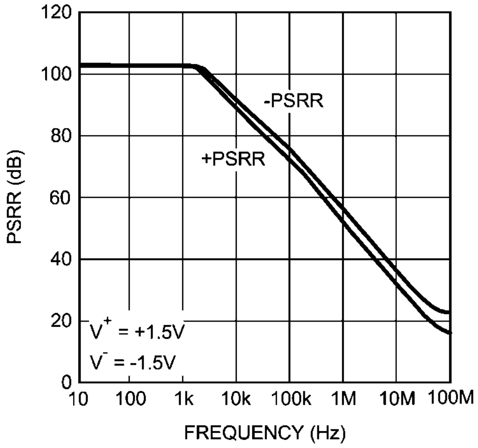
20195822

PSRR vs. Frequency



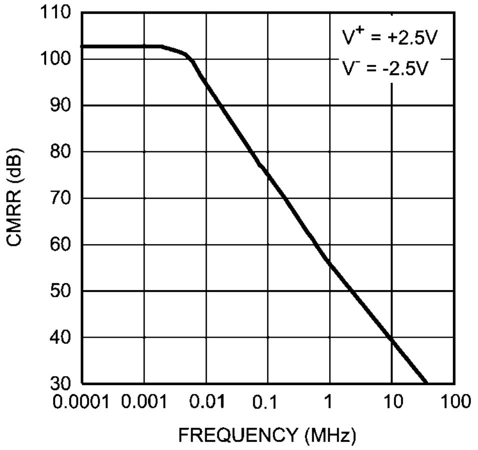
20195837

PSRR vs. Frequency



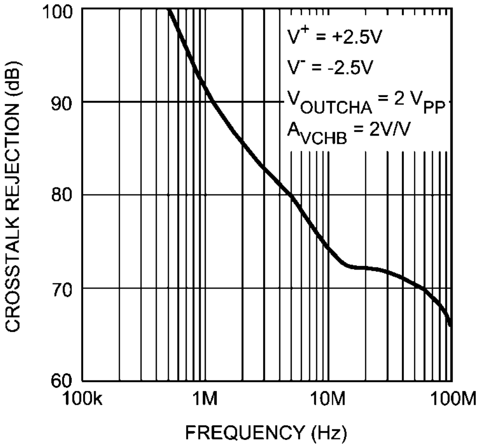
20195838

CMRR vs. Frequency



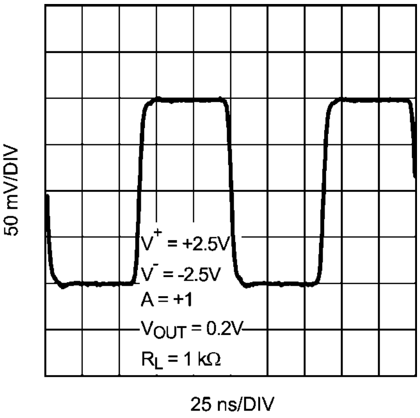
20195823

Crosstalk Rejection vs. Frequency (Output to Output)



20195879

Small Signal Step Response



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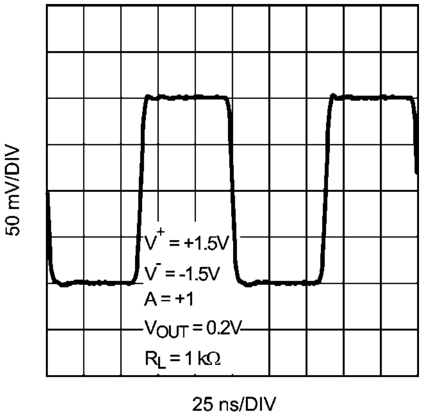

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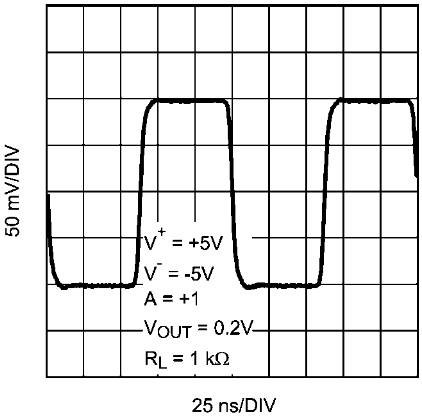
Small Signal Step Response



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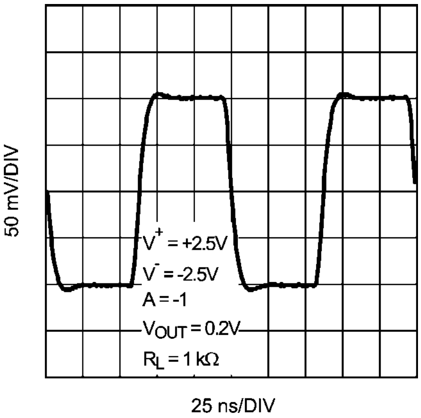
Small Signal Step Response



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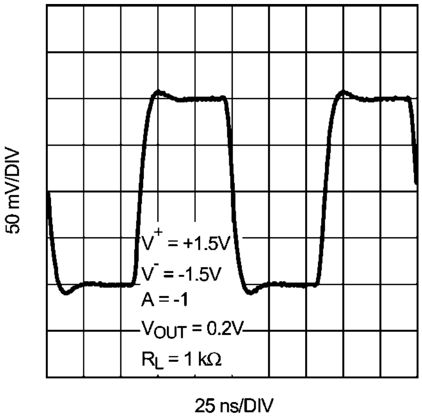
Small Signal Step Response



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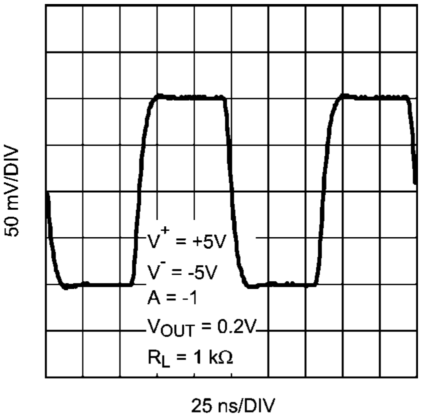

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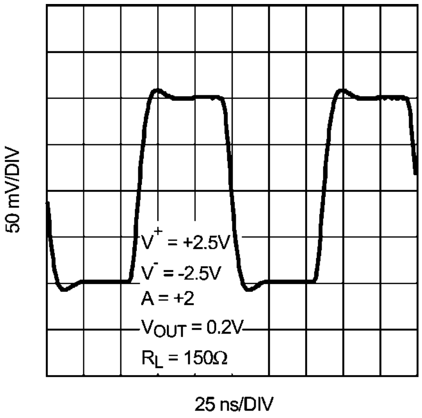
Small Signal Step Response



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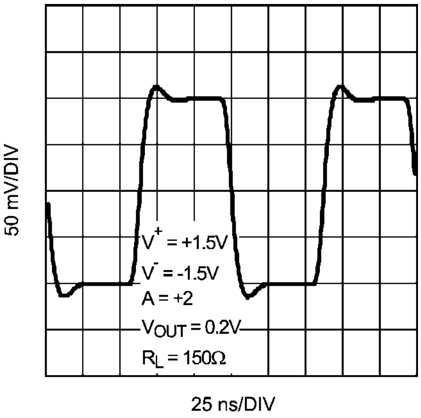
Small Signal Step Response



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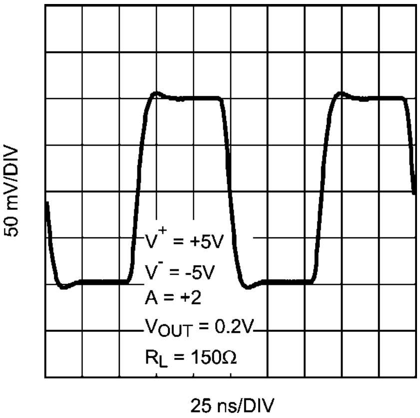
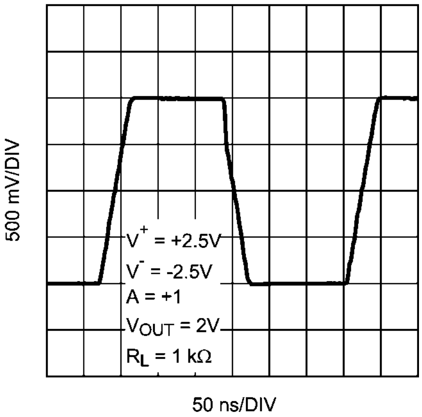
Small Signal Step Response



20195810

Large Signal Step Response



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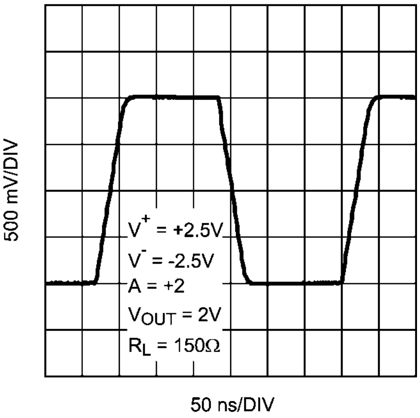
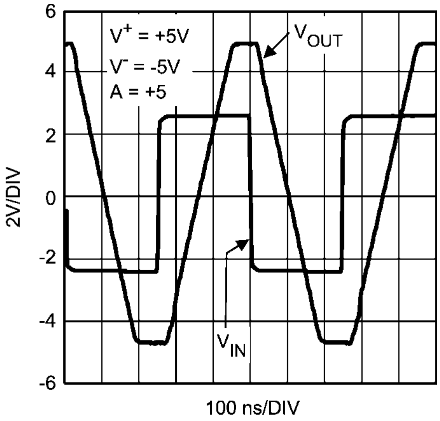
Large Signal Step Response



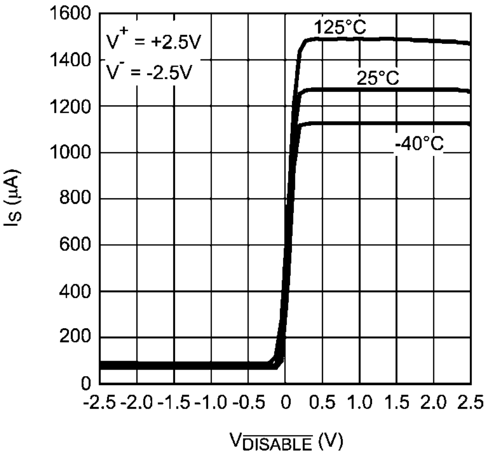
20195814

Overload Recovery Waveform



20195824

I_S vs. $V_{\overline{DISABLE}}$



20195861

Application Information

The LMH6618 and LMH6619 are based on National Semiconductor's proprietary VIP10 dielectrically isolated bipolar process. This device family architecture features the following:

- Complimentary bipolar devices with exceptionally high f_t (~8 GHz) even under low supply voltage (2.7V) and low bias current.
- Common emitter push-push output stage. This architecture allows the output to reach within millivolts of either supply rail.
- Consistent performance from any supply voltage $_{(2.7V - 11V)}$ with little variation with supply voltage for the most important specifications (e.g. BW, SR, I_{OUT}.)
- Significant power saving compared to competitive devices on the market with similar performance.

With 3V supplies and a common mode input voltage range that extends beyond either supply rail, the LMH6618 and LMH6619 are well suited to many low voltage/low power applications. Even with 3V supplies, the −3 dB BW (at A_V = +1) is typically 120 MHz.

The LMH6618 and LMH6619 are designed to avoid output phase reversal. With input over-drive, the output is kept near the supply rail (or as close to it as mandated by the closed loop gain setting and the input voltage). *Figure 1* shows the input and output voltage when the input voltage significantly exceeds the supply voltages.

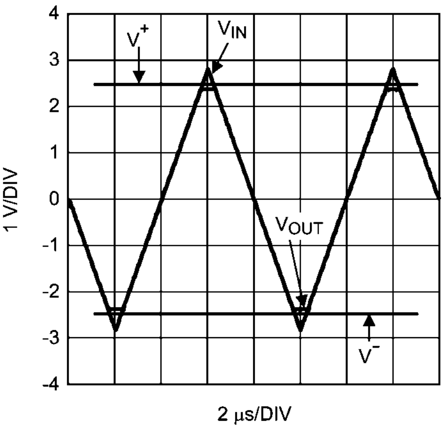


FIGURE 1. Input and Output Shown with CMVR Exceeded

If the input voltage range is exceeded by more than a diode drop beyond either rail, the internal ESD protection diodes will start to conduct. The current flow in these ESD diodes should be externally limited.

The LMH6618 can be shutdown by connecting the $\overline{\text{DISABLE}}$ pin to a voltage 0.5V below the supply midpoint which will reduce the supply current to typically less than 100 µA. The $\overline{\text{DISABLE}}$ pin is "active low" and should be connected through a resistor to V+ for normal operation. Shutdown is guaranteed when the $\overline{\text{DISABLE}}$ pin is 0.5V below the supply midpoint at any operating supply voltage and temperature.

In the shutdown mode, essentially all internal device biasing is turned off in order to minimize supply current flow and the output goes into high impedance mode. During shutdown, the input stage has an equivalent circuit as shown in *Figure 2*.

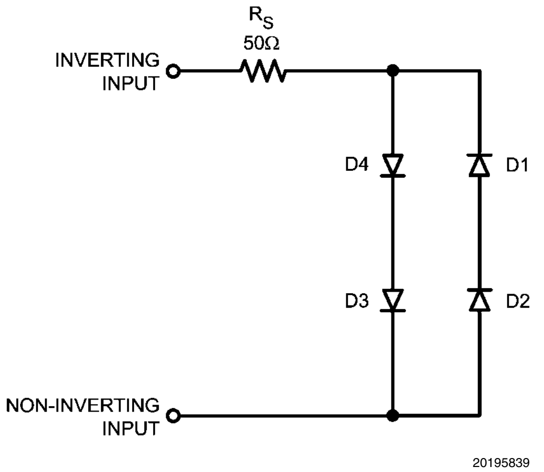


FIGURE 2. Input Equivalent Circuit During Shutdown

When the LMH6618 is shutdown, there may be current flow through the internal diodes shown, caused by input potential, if present. This current may flow through the external feedback resistor and result in an apparent output signal. In most shutdown applications the presence of this output is inconsequential. However, if the output is "forced" by another device, the other device will need to conduct the current described in order to maintain the output potential.

To keep the output at or near ground during shutdown when there is no other device to hold the output low, a switch using a transistor can be used to shunt the output to ground.

SINGLE CHANNEL ADC DRIVER

The low noise and wide bandwidth make the LMH6618 an excellent choice for driving a 12-bit ADC. *Figure 3* shows the schematic of the LMH6618 driving an ADC121S101. The ADC121S101 is a single channel 12-bit ADC. The LMH6618 is set up in a 2nd order multiple-feedback configuration with a gain of −1. The −3 dB point is at 500 kHz and the −0.01 dB point is at 100 kHz. The 22Ω resistor and 390 pF capacitor form an antialiasing filter for the ADC121S101. The capacitor also stores and delivers charge to the switched capacitor input of the ADC. The capacitive load on the LMH6618 created by the 390 pF capacitor is decreased by the 22Ω resistor. *Table 1* shows the performance data of the LMH6618 and the ADC121S101.

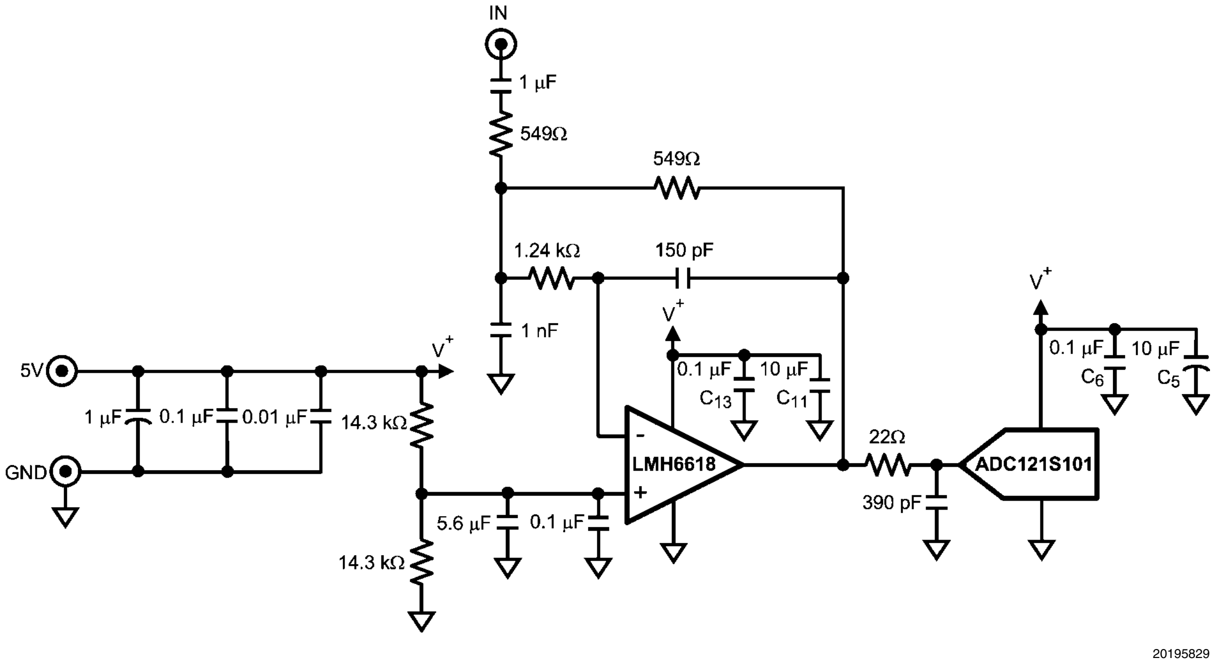


FIGURE 3. LMH6618 Driving an ADC121S101

TABLE 1. Performance Data for the LMH6618 Driving an ADC121S101

Parameter	Measured Value
Signal Frequency	100 kHz
Signal Amplitude	4.5V
SINAD	71.5 dB
SNR	71.87 dB
THD	−82.4 dB
SFDR	90.97 dB
ENOB	11.6 bits

When the op amp and the ADC are using the same supply, it is important that both devices are well bypassed. A 0.1 µF ceramic capacitor and a 10 µF tantalum capacitor should be located as close as possible to each supply pin. A sample layout is shown in *Figure 4*. The 0.1 µF capacitors (C13 and C6) and the 10 µF capacitors (C11 and C5) are located very close to the supply pins of the LMH6618 and the ADC121S101.

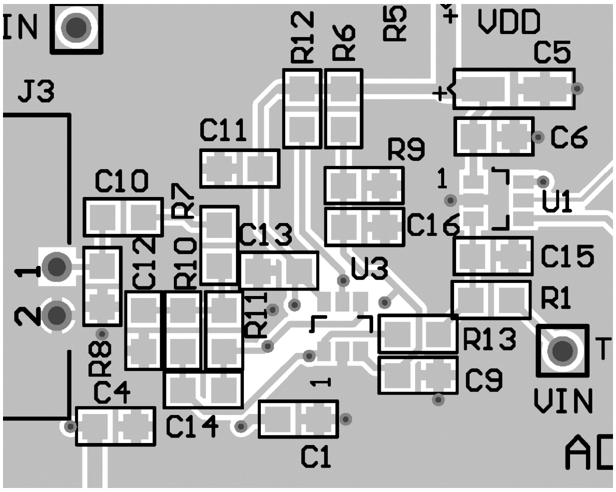


FIGURE 4. LMH6618 and ADC121S101 Layout

SINGLE TO DIFFERENTIAL ADC DRIVER

Figure 5 shows the LMH6619 used to drive a differential ADC with a single-ended input. The ADC121S625 is a fully differential 12-bit ADC. *Table 2* shows the performance data of the LMH6619 and the ADC121S625.

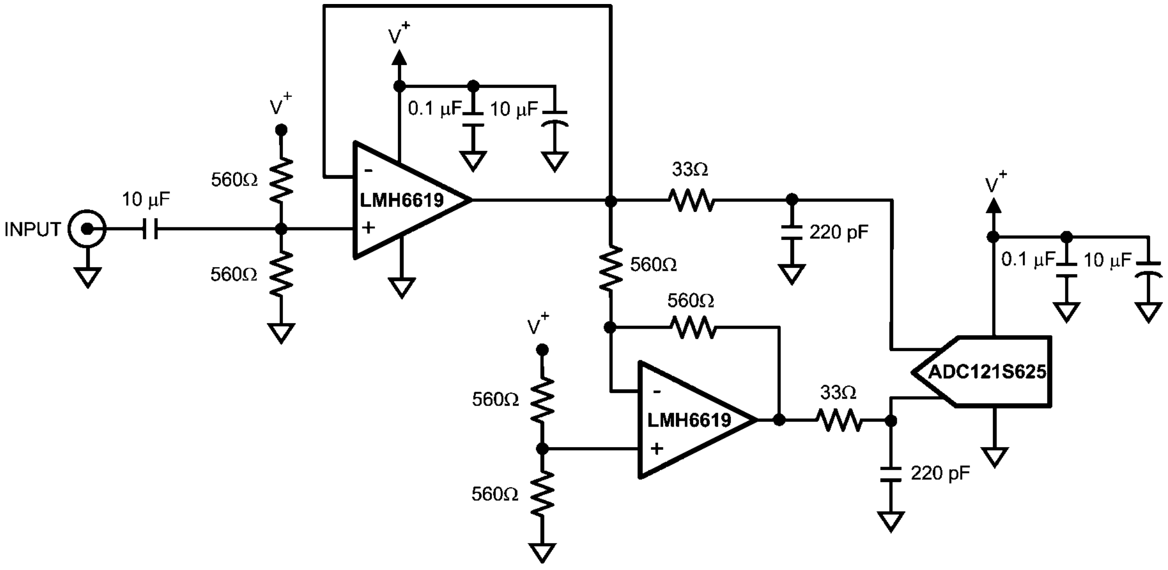


FIGURE 5. LMH6619 Driving an ADC121S625

TABLE 2. Performance Data for the LMH6619 Driving an ADC121S625

Parameter	Measured Value
Signal Frequency	10 kHz
Signal Amplitude	2.5V
SINAD	67.9 dB
SNR	68.29 dB
THD	−78.6 dB
SFDR	75.0 dB
ENOB	11.0 bits

DIFFERENTIAL ADC DRIVER

The circuit in *Figure 3* can be used to drive both inputs of a differential ADC. *Figure 6* shows the LMH6619 driving an ADC121S705. The ADC121S705 is a fully differential 12-bit ADC. Performance with this circuit is similar to the circuit in *Figure 3*.

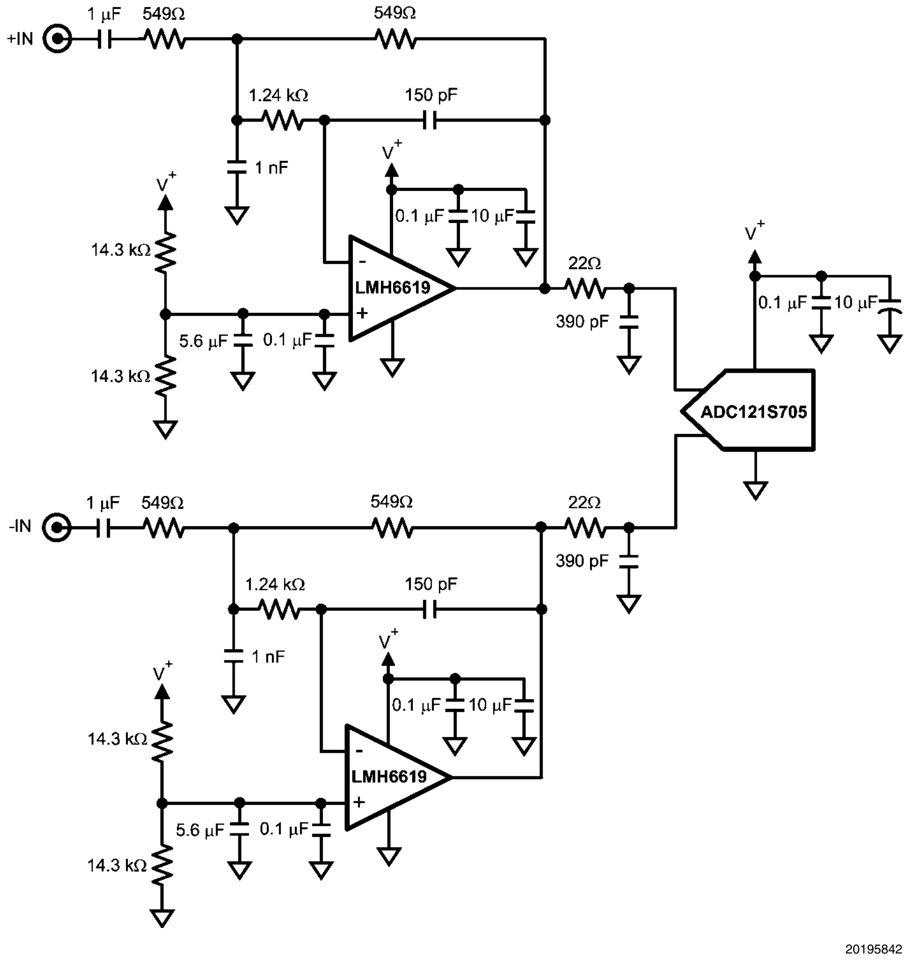


FIGURE 6. LMH6619 Driving an ADC121S705

DC LEVEL SHIFTING

Often a signal must be both amplified and level shifted while using a single supply for the op amp. The circuit in *Figure 7* can do both of these tasks. The procedure for specifying the resistor values is as follows.

1. Determine the input voltage.
2. Calculate the input voltage midpoint, $V_{INMID} = V_{INMIN} + (V_{INMAX} - V_{INMIN})/2$.
3. Determine the output voltage needed.
4. Calculate the output voltage midpoint, $V_{OUTMID} = V_{OUTMIN} + (V_{OUTMAX} - V_{OUTMIN})/2$.
5. Calculate the gain needed, gain = $(V_{OUTMAX} - V_{OUTMIN})/(V_{INMAX} - V_{INMIN})$
6. Calculate the amount the voltage needs to be shifted from input to output, $\Delta V_{OUT} = V_{OUTMID} - \text{gain} \times V_{INMID}$.
7. Set the supply voltage to be used.
8. Calculate the noise gain, noise gain = gain + $\Delta V_{OUT}/V_S$.
9. Set R_F.
10. Calculate R_1, $R_1 = R_F/\text{gain}$.
11. Calculate R_2, $R_2 = R_F/(\text{noise gain-gain})$.
12. Calculate R_G, $R_G = R_F/(\text{noise gain} - 1)$.

Check that both the V_{IN} and V_{OUT} are within the voltage ranges of the LMH6618.

The following example is for a V_{IN} of 0V to 1V with a V_{OUT} of 2V to 4V.

1. V_{IN} = 0V to 1V
2. $V_{INMID} = 0V + (1V - 0V)/2 = 0.5V$
3. V_{OUT} = 2V to 4V
4. $V_{OUTMID} = 2V + (4V - 2V)/2 = 3V$
5. Gain = (4V – 2V)/(1V – 0V) = 2
6. $\Delta V_{OUT} = 3V - 2 \times 0.5V = 2$
7. For the example the supply voltage will be +5V.
8. Noise gain = 2 + 2/5V = 2.4
9. $R_F = 2\ k\Omega$
10. $R_1 = 2\ k\Omega/2 = 1\ k\Omega$
11. $R_2 = 2\ k\Omega/(2.4-2) = 5\ k\Omega$
12. $R_G = 2\ k\Omega/(2.4 - 1) = 1.43\ k\Omega$

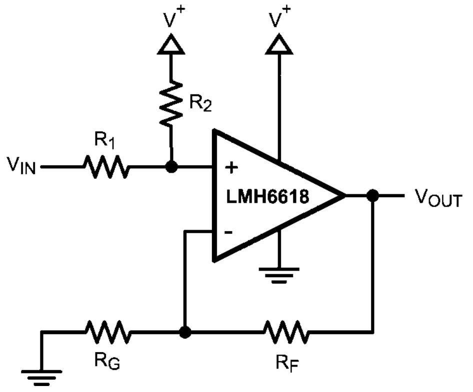


FIGURE 7. DC Level Shifting

4th ORDER MULTIPLE FEEDBACK LOW-PASS FILTER

Figure 8 shows the LMH6619 used as the amplifier in a multiple feedback low pass filter. This filter is set up to have a gain of +1 and a –3 dB point of 1 MHz. Values can be determined by using the WEBENCH® Active Filter Designer found at amplifiers.national.com.

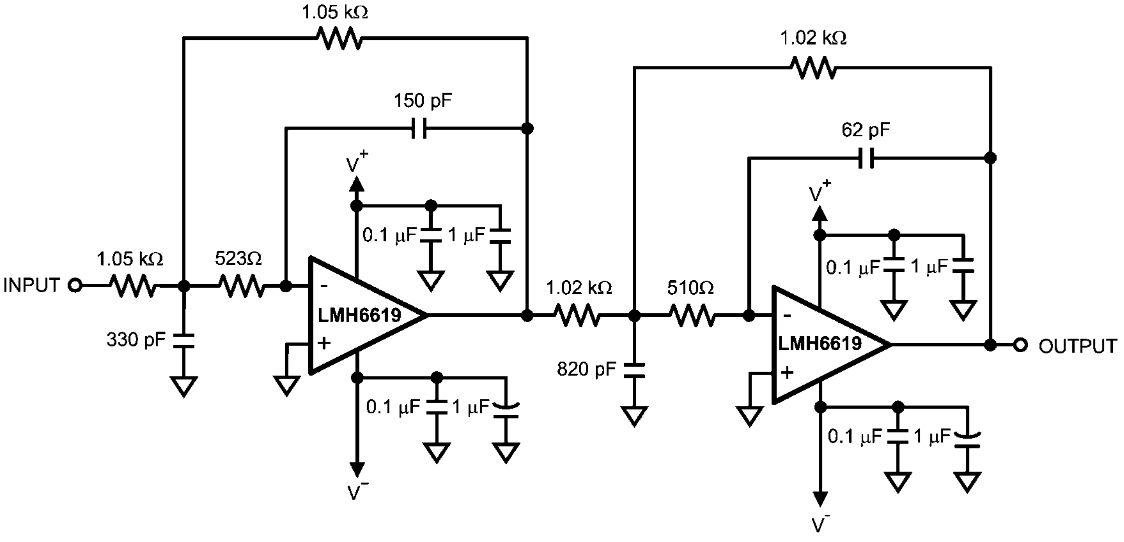


FIGURE 8. 4th Order Multiple Feedback Low-Pass Filter

CURRENT SENSE AMPLIFIER

With it's rail-to-rail input and output capability, low V_{OS}, and low I_B the LMH6618 is an ideal choice for a current sense amplifier application. *Figure 9* shows the schematic of the LMH6618 set up in a low-side sense configuration which provides a conversion gain of 2V/A. Voltage error due to V_{OS} can be calculated to be V_{OS} x (1 + R_F/R_G) or 0.6 mV x 21 = 12.6 mV. Voltage error due to I_O is I_O x R_F or 0.26 µA x 1 kΩ = 0.26 mV. Hence total voltage error is 12.6 mV + 0.26 mV or 12.86 mV which translates into a current error of 12.86 mV/(2 V/A) = 6.43 mA.

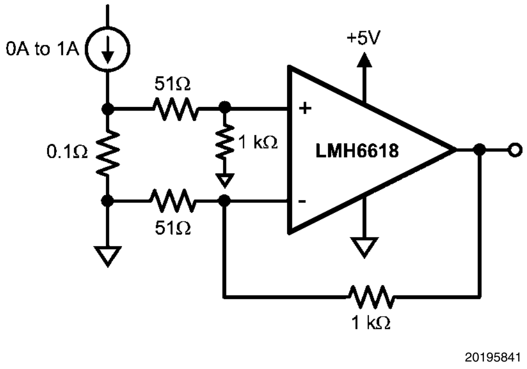


FIGURE 9. Current Sense Amplifier

TRANSIMPEDANCE AMPLIFIER

By definition, a photodiode produces either a current or voltage output from exposure to a light source. A Transimpedance Amplifier (TIA) is utilized to convert this low-level current to a usable voltage signal. The TIA often will need to be compensated to insure proper operation.

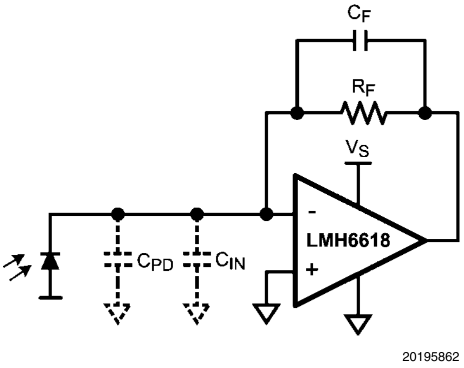


FIGURE 10. Photodiode Modeled with Capacitance Elements

Figure 10 shows the LMH6618 modeled with photodiode and the internal op amp capacitances. The LMH6618 allows circuit operation of a low intensity light due to its low input bias current by using larger values of gain (R_F). The total capacitance (C_T) on the inverting terminal of the op amp includes the photodiode capacitance (C_{PD}) and the input capacitance of the op amp (C_{IN}). This total capacitance (C_T) plays an important role in the stability of the circuit. The noise gain of this circuit determines the stability and is defined by:

$$NG = \frac{1 + sR_F(C_T + C_F)}{1 + sC_FR_F} \tag{1}$$

$$\text{Where, } f_Z \cong \frac{1}{2\pi R_FC_T} \text{ and } f_P = \frac{1}{2\pi R_FC_F} \tag{2}$$

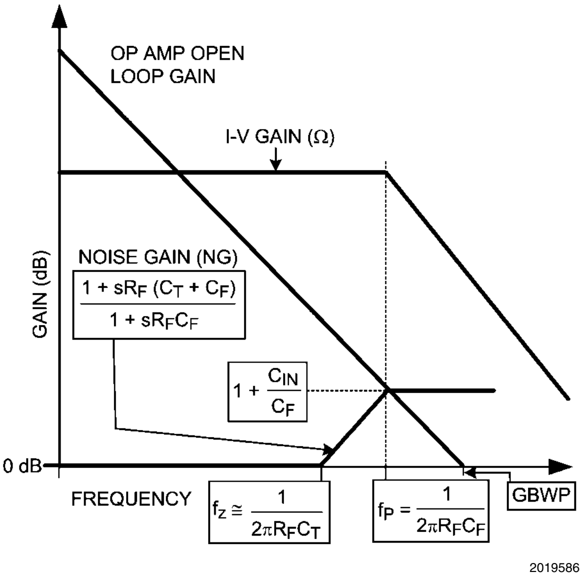


FIGURE 11. Bode Plot of Noise Gain Intersecting with Op Amp Open-Loop Gain

Figure 11 shows the bode plot of the noise gain intersecting the op amp open loop gain. With larger values of gain, C_T and R_F create a zero in the transfer function. At higher frequencies the circuit can become unstable due to excess phase shift around the loop.

A pole at f_P in the noise gain function is created by placing a feedback capacitor (C_F) across R_F. The noise gain slope is flattened by choosing an appropriate value of C_F for optimum performance.

Theoretical expressions for calculating the optimum value of C_F and the expected –3 dB bandwidth are:

$$C_F = \sqrt{\frac{C_T}{2\pi R_F(GBWP)}} \tag{3}$$

$$f_{-3\text{ dB}} = \sqrt{\frac{GBWP}{2\pi R_FC_T}} \tag{4}$$

Equation 4 indicates that the –3 dB bandwidth of the TIA is inversely proportional to the feedback resistor. Therefore, if the bandwidth is important then the best approach would be to have a moderate transimpedance gain stage followed by a broadband voltage gain stage.

Table 3 shows the measurement results of the LMH6618 with different photodiodes having various capacitances (C_{PD}) and a feedback resistance (R_F) of 1 kΩ.

TABLE 3. TIA (Figure 1) Compensation and Performance Results

C_{PD}	C_T	$C_{F\ CAL}$	$C_{F\ USED}$	$f_{-3\ dB\ CAL}$	$f_{-3\ dB\ MEAS}$	Peaking
(pF)	(pF)	(pF)	(pF)	(MHz)	(MHz)	(dB)
22	24	7.7	5.6	23.7	20	0.9
47	49	10.9	10	16.6	15.2	0.8
100	102	15.8	15	11.5	10.8	0.9
222	224	23.4	18	7.81	8	2.9

Note:
GBWP = 65 MHz
$C_T = C_{PD} + C_{IN}$
C_{IN} = 2 pF
$V_S = \pm 2.5V$

Figure 12 shows the frequency response for the various photodiodes in *Table 3*.

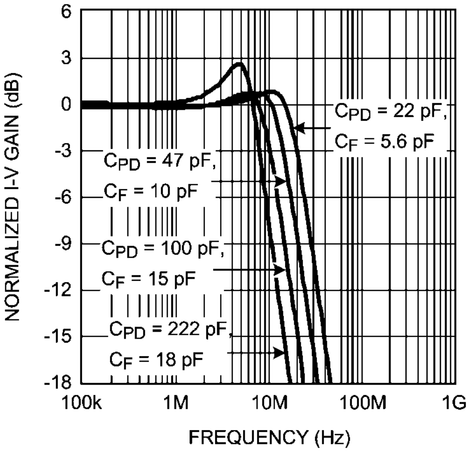


FIGURE 12. Frequency Response for Various Photodiode and Feedback Capacitors

When analyzing the noise at the output of the TIA, it is important to note that the various noise sources (i.e. op amp noise voltage, feedback resistor thermal noise, input noise current, photodiode noise current) do not all operate over the same frequency band. Therefore, when the noise at the output is calculated, this should be taken into account. The op amp noise voltage will be gained up in the region between the noise gain's zero and pole (f_Z and f_P in *Figure 11*). The higher the values of R_F and C_T, the sooner the noise gain peaking starts and therefore its contribution to the total output noise will be larger. It is obvious to note that it is advantageous to minimize C_{IN} by proper choice of op amp or by applying a reverse bias across the diode at the expense of excess dark current and noise.

DIFFERENTIAL CABLE DRIVER FOR NTSC VIDEO

The LMH6618 and LMH6619 can be used to drive an NTSC video signal on a twisted-pair cable. *Figure 13* shows the schematic of a differential cable driver for NTSC video. This circuit can be used to transmit the signal from a camera over a twisted pair to a monitor or display located a distance. C_1 and C_2 are used to AC couple the video signal into the LMH6619. The two amplifiers of the LMH6619 are set to a gain of 2 to compensate for the 75Ω back termination resistors on the outputs. The LMH6618 is set to a gain of 1. Because of the DC bias the output of the LMH6618 is AC coupled. Most monitors and displays will accept AC coupled inputs.

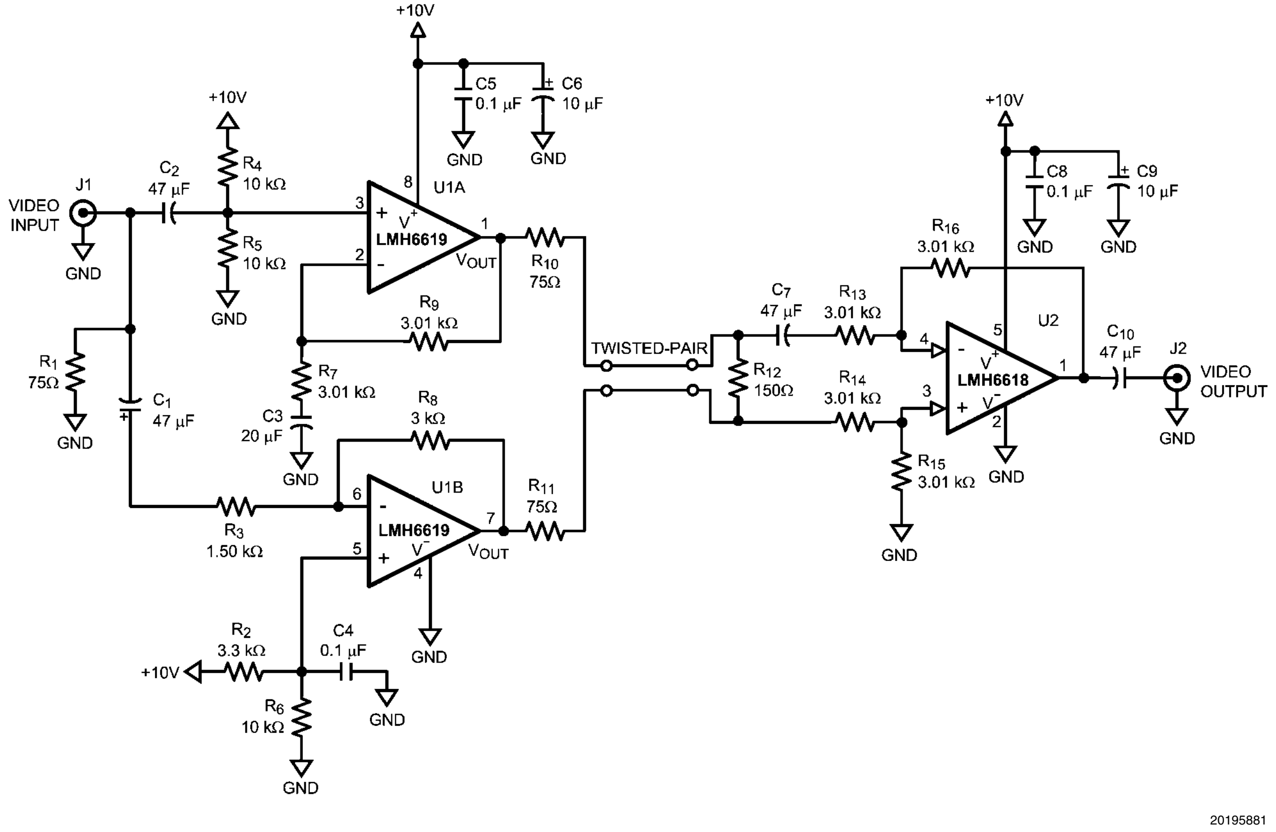
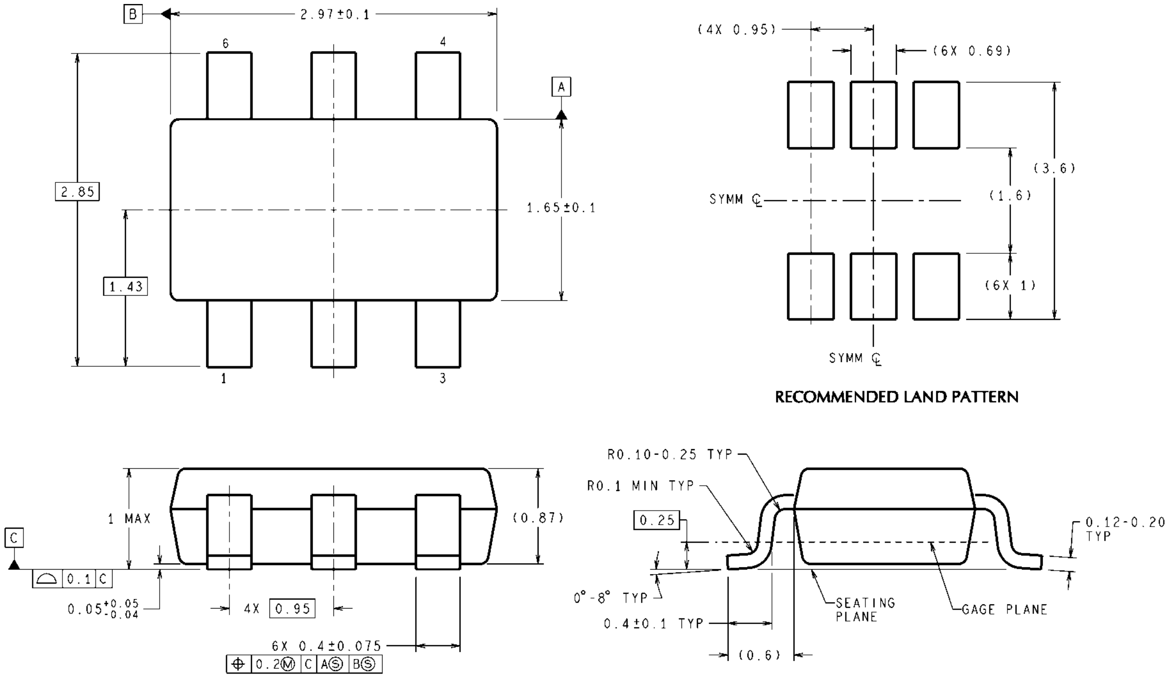


FIGURE 13. Differential Cable Driver

Physical Dimensions inches (millimeters) unless otherwise noted



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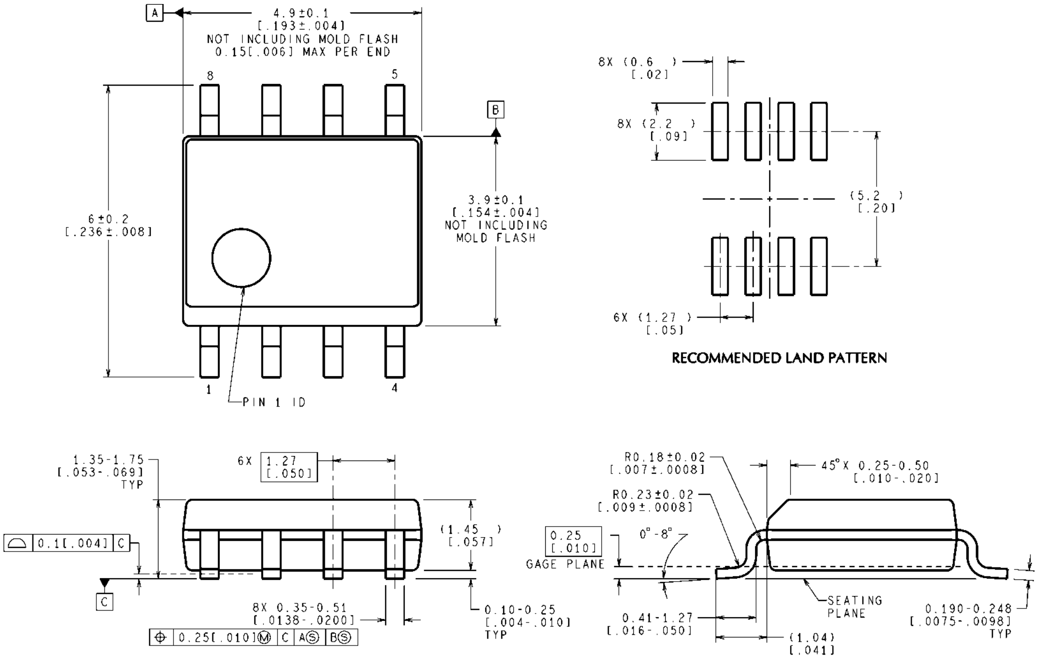

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